TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MET540AFK,TC7MET541AFK

Octal Bus Buffer TC7MET540AFK Inverted, 3-State Outputs

TC7MET541AFK Non-Inverted, 3-State Outputs

The TC7MET540AFK and 541AFK are advanced high speed CMOS octal bus buffers fabricated with silicon gate C^2MOS technology. They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

The TC7MET540AFK is an inverting type and, the TC7MET541AFK is a non-inverting type.

When either $\overline{G}1$ or $\overline{G}2$ are high , the terminal outputs are in the high-impedance state.

The input voltage are compatible with TTL output voltage.

These devices may be used as a level converter for interfacing

 $3.3\ \mathrm{V}$ to $5\ \mathrm{V}$ system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (*) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

*: output in off-state

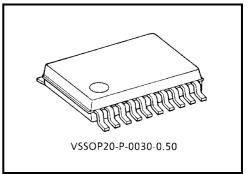
Features

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- High speed: $t_{pd} = 5.4 \text{ ns} (typ.) (V_{CC} = 5 \text{ V})$
- Low power dissipation: $ICC = 4 \mu A (max) (Ta = 25 \circ C)$
 - Compatible with TTL outputs: $V_{IL} = 0.8 V (max)$

 $V_{IH} = 2.0 V (min)$

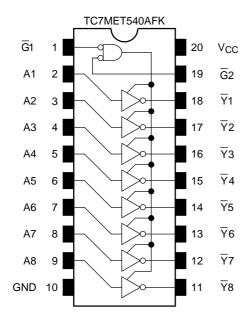
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays: $t_{pLH}\approx t_{pHL}$
- Low noise: VOLP = 1.5 V (max)
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 540/541 type.



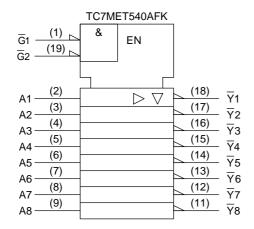
Weight: 0.03 g (typ.)

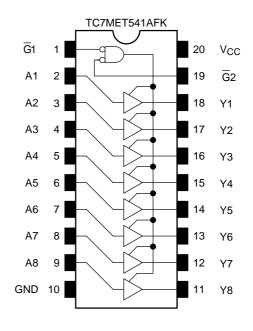
<u>TOSHIBA</u>

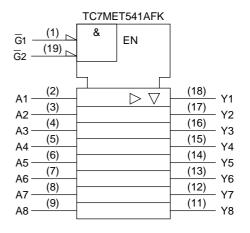
Pin Assignment (top view)



IEC Logic Symbol







Truth Table

	Inputs	Outputs				
G1	G2	A _n	Yn	\overline{Y}_n		
Н	Х	Х	Z	Z		
Х	Н	Х	Z	Z		
L	L	Н	Н	L		
L	L	L	L	Н		

X: Don't care

Z: High impedance

Y_n: TC7MET541AFK

 \overline{Y}_n : TC7MET540AFK

Maximum Ratings

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	-0.5~7.0	V	
DC input voltage	V _{IN}	-0.5~7.0	V	
DC output voltage		–0.5~7.0 (Note1)	V	
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5 (Note2)	v	
Input diode current	I _{IK}	-20	mA	
Output diode current	I _{OK}	±20 (Note3)	mA	
DC output current	IOUT	±25	mA	
DC V _{CC} /ground current	ICC	±75	mA	
Power dissipation	PD	180	mW	
Storage temperature	T _{stg}	-65~150	°C	

Note1: Output in off-state

Note2: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note3: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	4.5~5.5	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	Vour	0~5.5 (Note4)	V	
Output voltage	Vout	0~V _{CC} (Note5)	v	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~20	ns/V	

Note4: Output in off-state

Note5: High or low state

Electrical Characteristics

DC Characteristics

Characteristics		Symbol Test Condition		Condition		Ta = 25°C			Ta = -40~85°C		Unit
		Symbol	Test	Test Condition		Min	Тур.	Max	Min	Max	Unit
Input voltage	High level	VIH		_	4.5~5.5	2.0			2.0	_	V
mput voltage	low level	VIL		_	4.5~5.5			0.8	—	0.8	v
	Vон	$V_{IN} = V_{IH}$	$I_{OH} = -50 \ \mu A$	4.5	4.4	4.5	_	4.4	_		
High level		VОН	or V _{IL}	$I_{OH} = -8 \text{ mA}$	4.5	3.94			3.80		_
Output voltage	low level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50 \ \mu A$	4.5		0	0.1		0.1	V
		VOL		$I_{OL} = 8 \text{ mA}$	4.5			0.36	—	0.44	
3-state output off-state current		I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		5.5			±0.25	_	±2.50	μA
Input leakage cu	urrent	I _{IN}	$V_{IN} = 5.5 V \text{ or GND}$		0~5.5		_	±0.1		±1.0	μA
Quiescent supply current		ICC	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	_	40.0	μA
		I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	_	1.35	_	1.50	mA
Output leakage	current	I _{OPD}	V _{OUT} = 5.5 V		0	_		0.5		5.0	μA

AC Electrical Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	t Condition		Ta = 25°C			Ta = -40~85°C		Unit
Grandetensites Gymbol		Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time	t _{pLH}		5.0 ± 0.5	15		5.4	7.4	1.0	8.5	ns
(TC7MET540AFK)	t _{pHL}		5.0 ± 0.5	50		5.9	8.4	1.0	9.5	115
Propagation delay time	t _{pLH}		5.0 ± 0.5	15		5.0	6.9	1.0	8.0	ns
(TC7MET541AFK)	t _{pHL}		5.0 ± 0.5	50		5.5	7.9	1.0	9.0	
3-state output enable time	t _{pZL}	$R_L = 1 k\Omega$	5.0 ± 0.5	15	_	8.3	11.3	1.0	13.0	ns
	t _{pZH}	NL - 1 K22		50		8.8	12.3	1.0	14.0	
3-state output disable time	t _{pLZ}	$R_L = 1 k\Omega$	5.0 ± 0.5	50		9.4	11.9	1.0	13.5	ns
	t _{pHZ}		5.0 ± 0.5	50		0.4	11.5	1.0	15.5	113
Output to output skew	t _{osLH}	(Note6)	5.0 ± 0.5	50			1.0		1.0	ns
	tosHL		0.0 = 0.0	00			1.0		1.0	110
Input capacitance	C _{IN}				4	10	_	10	pF	
Output capacitance	C _{OUT}			_	9	_		—	pF	
Power dissipation capacitance	C _{PD}			(Note7)		19			_	pF

Note6: Parameter guaranteed by design.

 $t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|$

Note7: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per bit)$

Noise Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

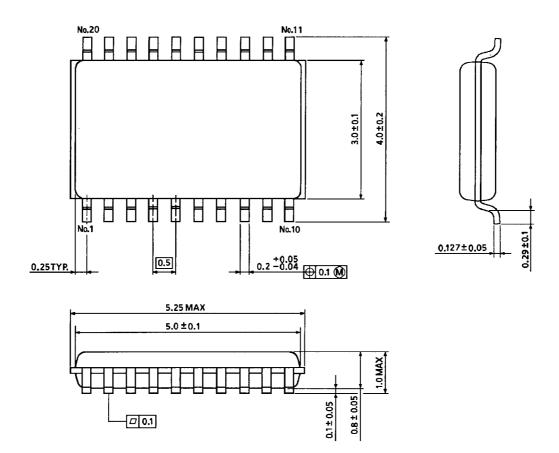
Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
Characteristics	Symbol	Test Condition	$V_{CC}\left(V\right)$	Тур.	Limit	Onit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$C_L = 50 \text{ pF}$	5.0	1.1	1.5	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$C_L = 50 \text{ pF}$	5.0	-1.1	-1.5	V
Minimum high level dynamic input voltage V_{IH}	V _{IHD}	$C_L = 50 \text{ pF}$	5.0	_	2.0	V
Maximum low level dynamic input voltage V_{IL}	V _{ILD}	C _L = 50 pF	5.0		0.8	V



Package Dimensions

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)

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Handbook" etc..

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